

**Power Products Division**

*Advance Information*

**HALF-BRIDGE DRIVER**

The MPIC2111 is a high voltage, high speed, power MOSFET and IGBT driver with dependent high and low side referenced output channels designed for half-bridge applications. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. Logic input is compatible with standard CMOS outputs. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. Internal deadtime is provided to avoid shoot-through in the output half-bridge. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates from 10 to 600 volts.

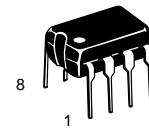
- Floating Channel Designed for Bootstrap Operation
- Fully Operational to +600 V
- Tolerant to Negative Transient Voltage
- dV/dt Immune
- Gate Drive Supply Range from 10 to 20 V
- Undervoltage Lockout for Both Channels
- CMOS Schmitt-triggered Inputs with Pull-down
- Matched Propagation Delay for Both Channels
- Internally Set Deadtime
- High Side Output in Phase with Input

**PRODUCT SUMMARY**

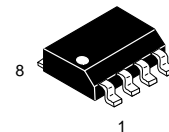
|                                     |                        |
|-------------------------------------|------------------------|
| <b>V<sub>OFFSET</sub></b>           | <b>600 V MAX</b>       |
| <b>I<sub>O+/-</sub></b>             | <b>200 mA/420 mA</b>   |
| <b>V<sub>OUT</sub></b>              | <b>10 – 20 V</b>       |
| <b>t<sub>on/off</sub> (typical)</b> | <b>130 &amp; 90 ns</b> |
| <b>Deadtime (typical)</b>           | <b>700 ns</b>          |

**MPIC2111**

**HALF-BRIDGE DRIVER**



**P SUFFIX**  
PLASTIC PACKAGE  
CASE 626-05



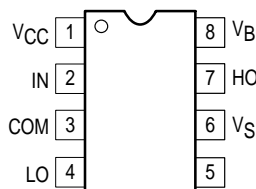
**D SUFFIX**  
PLASTIC PACKAGE  
CASE 751-05  
(SO-8)

**ORDERING INFORMATION**

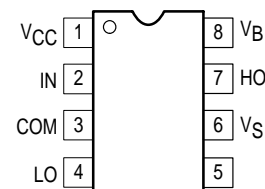
| Device    | Package |
|-----------|---------|
| MPIC2111D | SOIC    |
| MPIC2111P | PDIP    |

**PIN CONNECTIONS**

(TOP VIEW)



8 LEADS DIP  
MPIC2111P

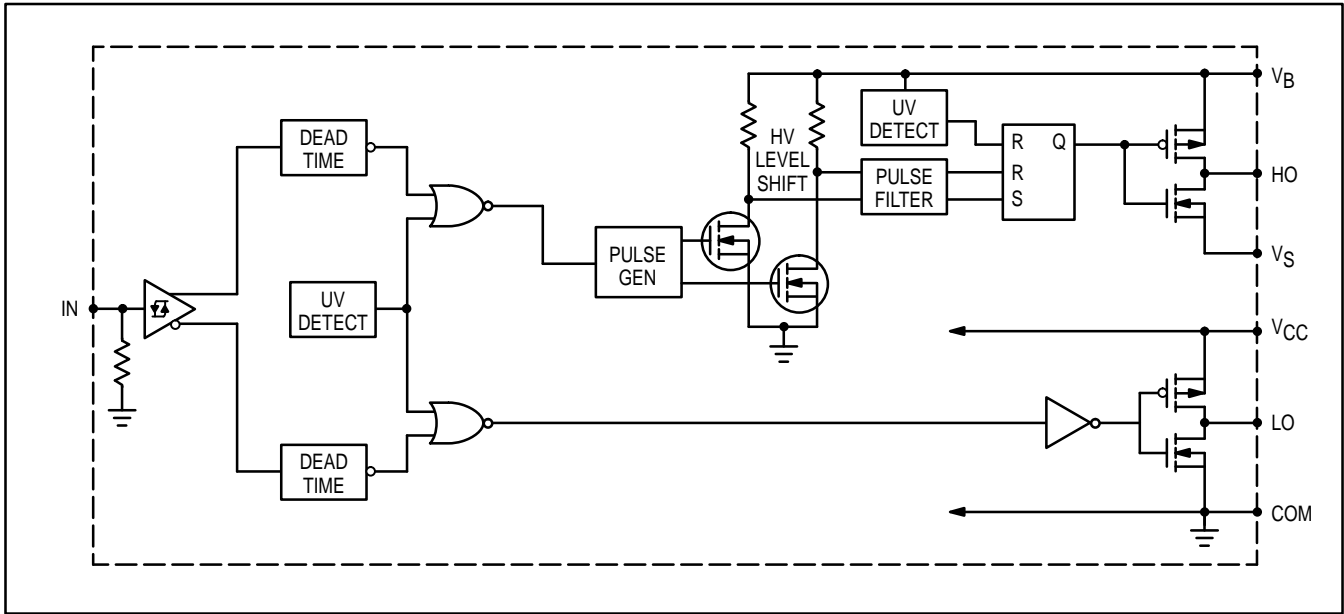


8 LEAD SOIC  
MPIC2111D

This document contains information on a new product. Specifications and information herein are subject to change without notice.

REV 1

SIMPLIFIED BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The Thermal Resistance and Power Dissipation ratings are measured under board mounted and still air conditions.

| Rating  | Symbol                            | Min                 | Max                  | Unit            |
|---|-----------------------------------|---------------------|----------------------|-----------------|
| High Side Floating Supply Absolute Voltage          | V <sub>B</sub>                    | -0.3                | 625                  | V <sub>DC</sub> |
| High Side Floating Supply Offset Voltage            | V <sub>S</sub>                    | V <sub>B</sub> -25  | V <sub>B</sub> +0.3  |                 |
| High Side Floating Output Voltage                   | V <sub>HO</sub>                   | V <sub>S</sub> -0.3 | V <sub>B</sub> +0.3  |                 |
| Low Side Fixed Supply Voltage                       | V <sub>CC</sub>                   | -0.3                | 25                   |                 |
| Low Side Output Voltage                             | V <sub>LO</sub>                   | -0.3                | V <sub>CC</sub> +0.3 |                 |
| Logic Input Voltage                                 | V <sub>IN</sub>                   | -0.3                | V <sub>CC</sub> +0.3 |                 |
| Allowable Offset Supply Voltage Transient           | dV <sub>S</sub> /dt               | -                   | 50                   | V/ns            |
| *Package Power Dissipation @ T <sub>C</sub> ≤ +25°C | P <sub>D</sub>                    | -                   | 1.0                  | Watt            |
|   |                                   | -                   | 0.625                |                 |
| Thermal Resistance, Junction to Ambient             | R <sub>θJA</sub>                  | -                   | 125                  | °C/W            |
|   |                                   | -                   | 200                  |                 |
| Operating and Storage Temperature                   | T <sub>j</sub> , T <sub>stg</sub> | -55                 | 150                  | °C              |
| Lead Temperature for Soldering Purposes, 10 seconds | T <sub>L</sub>                    | -                   | 260                  | °C              |

RECOMMENDED OPERATING CONDITIONS

The Input/Output logic timing Diagram is shown in Figure 1. For proper operation the device should be used within the recommended conditions. The V<sub>S</sub> offset rating is tested with all supplies biased at 15 V differential.

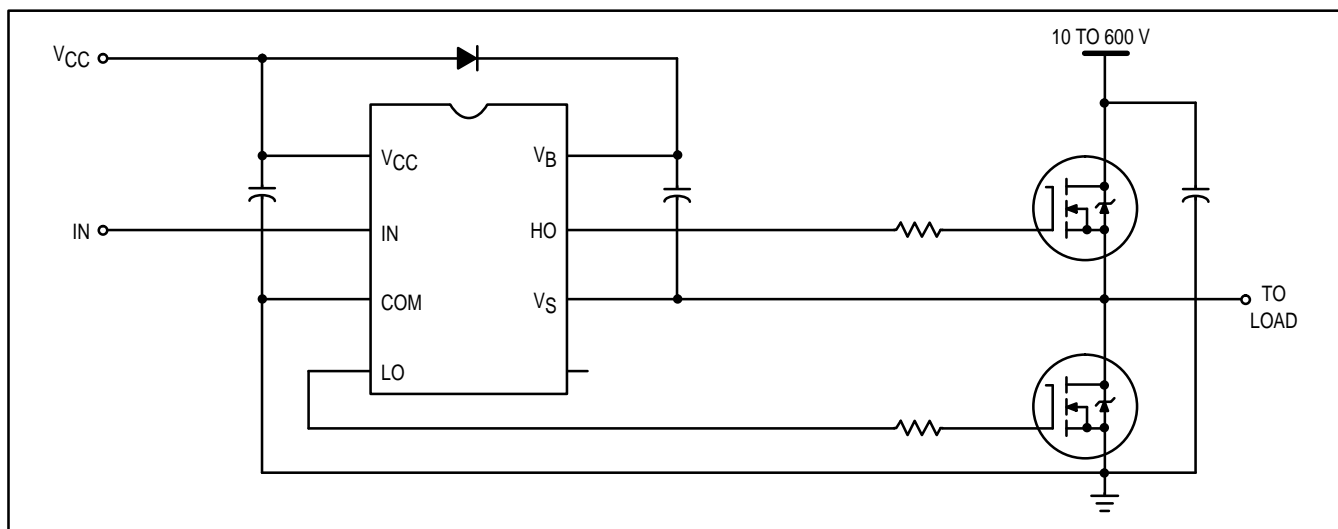
|  |                 |                    |                    |    |
|--|-----------------|--------------------|--------------------|----|
| High Side Floating Supply Absolute Voltage | V <sub>B</sub>  | V <sub>S</sub> +10 | V <sub>S</sub> +20 | V  |
| High Side Floating Supply Offset Voltage   | V <sub>S</sub>  | Note 1             | 600                |    |
| High Side Floating Output Voltage          | V <sub>HO</sub> | V <sub>S</sub>     | V <sub>B</sub>     |    |
| Low Side Fixed Supply Voltage              | V <sub>CC</sub> | 10                 | 20                 | mA |
| Low Side Output Voltage                    | V <sub>LO</sub> | 0                  | V <sub>CC</sub>    |    |
| Logic Input Voltage                        | V <sub>IN</sub> | 0                  | V <sub>CC</sub>    |    |
| Ambient Temperature                        | T <sub>A</sub>  | -40                | 125                | °C |

Note 1: Logic operational for V<sub>S</sub> of -5 to +600 V. Logic state held for V<sub>S</sub> of -5 V to -V<sub>BS</sub>.

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise specified)

| Characteristic  | Symbol             | Min  | Typ | Max | Unit            |
|---|--------------------|------|-----|-----|-----------------|
| <b>STATIC ELECTRICAL CHARACTERISTICS</b>  |                    |      |     |     |                 |
| V <sub>BIAS</sub> (V <sub>CC</sub> , V <sub>BS</sub> ) = 15 V unless otherwise specified. The V <sub>IN</sub> , V <sub>TH</sub> and I <sub>IN</sub> parameters are referenced to COM. The V <sub>O</sub> and I <sub>O</sub> parameters are referenced to COM and are applicable to the respective output leads: HO or LO. |                    |      |     |     |                 |
| Logic "1" Input Voltage for HO & Logic "0" Input Voltage for LO @ V <sub>CC</sub> = 10 V  | V <sub>IH</sub>    | 6.4  | –   | –   | V <sub>DC</sub> |
| Logic "1" Input Voltage for HO & Logic "0" Input Voltage for LO @ V <sub>CC</sub> = 15 V  | V <sub>IH</sub>    | 9.5  | –   | –   |                 |
| Logic "1" Input Voltage for HO & Logic "0" Input Voltage for LO @ V <sub>CC</sub> = 20 V  | V <sub>IH</sub>    | 12.6 | –   | –   |                 |
| Logic "0" Input Voltage for HO & Logic "1" Input Voltage for LO @ V <sub>CC</sub> = 10 V  | V <sub>IL</sub>    | –    | –   | 3.8 |                 |
| Logic "0" Input Voltage for HO & Logic "1" Input Voltage for LO @ V <sub>CC</sub> = 15 V  | V <sub>IL</sub>    | –    | –   | 6.0 |                 |
| Logic "0" Input Voltage for HO & Logic "1" Input Voltage for LO @ V <sub>CC</sub> = 20 V  | V <sub>IL</sub>    | –    | –   | 8.3 |                 |
| High Level Output Voltage, V <sub>BIAS</sub> -V <sub>O</sub> @ I <sub>O</sub> = 0 A   | V <sub>OH</sub>    | –    | –   | 100 | mV              |
| Low Level Output Voltage, V <sub>O</sub> @ I <sub>O</sub> = 0 A   | V <sub>OL</sub>    | –    | –   | 100 |                 |
| Offset Supply Leakage Current @ V <sub>B</sub> = V <sub>S</sub> = 600 V   | I <sub>LK</sub>    | –    | –   | 50  | μA              |
| Quiescent V <sub>BS</sub> Supply Current @ V <sub>IN</sub> = 0 V or V <sub>CC</sub>   | I <sub>QBS</sub>   | –    | 50  | –   |                 |
| Quiescent V <sub>CC</sub> Supply Current @ V <sub>IN</sub> = 0 V or V <sub>CC</sub>   | I <sub>QCC</sub>   | –    | 70  | –   |                 |
| Logic "1" Input Bias Current @ V <sub>IN</sub> = 15 V   | I <sub>IN+</sub>   | –    | 20  | 40  |                 |
| Logic "0" Input Bias Current @ V <sub>IN</sub> = 0 V  | I <sub>IN-</sub>   | –    | –   | 1.0 |                 |
| V <sub>BS</sub> Supply Undervoltage Positive Going Threshold  | V <sub>BSUV+</sub> | –    | 8.5 | –   |                 |
| V <sub>BS</sub> Supply Undervoltage Negative Going Threshold  | V <sub>BSUV-</sub> | –    | 8.2 | –   |                 |
| V <sub>CC</sub> Supply Undervoltage Positive Going Threshold  | V <sub>CCUV+</sub> | –    | 8.6 | –   |                 |
| V <sub>CC</sub> Supply Undervoltage Negative Going Threshold  | V <sub>CCUV-</sub> | –    | 8.2 | –   |                 |
| Output High Short Circuit Pulsed Current @ V <sub>OUT</sub> = 0 V, PW ≤ 10 μs   | I <sub>O+</sub>    | 200  | 250 | –   | mA              |
| Output Low Short Circuit Pulsed Current @ V <sub>OUT</sub> = 15 V, PW ≤ 10 μs   | I <sub>O-</sub>    | 420  | 500 | –   |                 |
| <b>DYNAMIC ELECTRICAL CHARACTERISTICS</b>   |                    |      |     |     |                 |
| V <sub>BIAS</sub> (V <sub>CC</sub> , V <sub>BS</sub> ) = 15 V unless otherwise specified  |                    |      |     |     |                 |
| Turn-On Propagation Delay @ V <sub>S</sub> = 0 V  | t <sub>on</sub>    | –    | 850 | –   | ns              |
| Turn-Off Propagation Delay @ V <sub>S</sub> = 600 V   | t <sub>off</sub>   | –    | 150 | –   |                 |
| Turn-On Rise Time @ C <sub>L</sub> = 1000 pF  | t <sub>r</sub>     | –    | 80  | –   |                 |
| Turn-Off Fall Time @ C <sub>L</sub> = 1000 pF   | t <sub>f</sub>     | –    | 40  | –   |                 |
| Deadtime, LS Turn-Off to HS Turn-On & HS Turn-Off to LS Turn-On   | DT                 | –    | 700 | –   |                 |
| Delay Matching, HS & LS Turn-On/Off   | MT                 | –    | 30  | –   |                 |

**TYPICAL CONNECTION**



# MPIC2111

## LEAD DEFINITIONS

| Symbol          | Lead Description   |
|-----------------|--|
| IN              | Logic Input for High Side and Low Side Gate Driver Outputs (HO & LO), In Phase with HO |
| V <sub>B</sub>  | High Side Floating Supply  |
| HO              | High Side Gate Drive Output  |
| V <sub>S</sub>  | High Side Floating Supply Return   |
| V <sub>CC</sub> | Low Side Supply  |
| L <sub>O</sub>  | Low Side Gate Drive Output   |
| COM             | Logic and Low Side Return  |

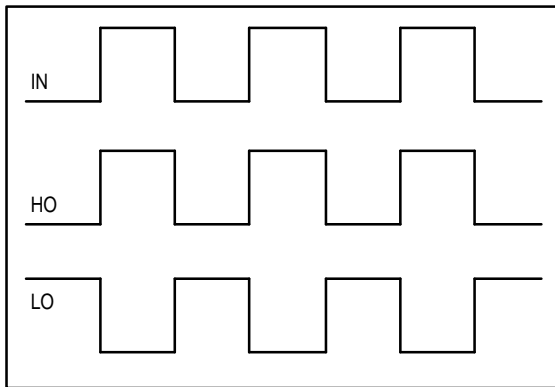


Figure 1. Input / Output Timing Diagram

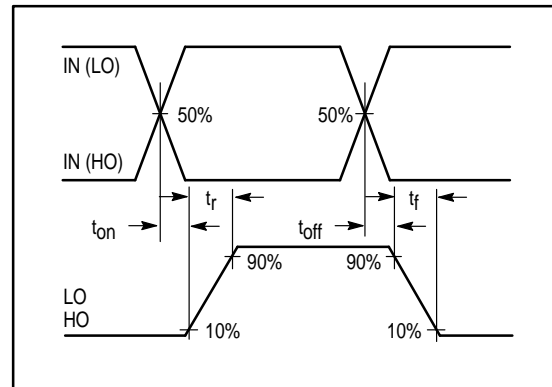


Figure 2. Switching Time Waveform Definitions

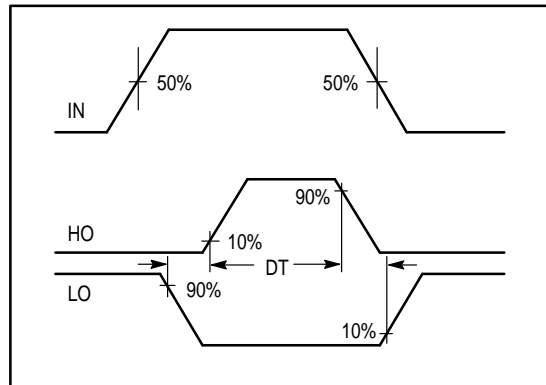
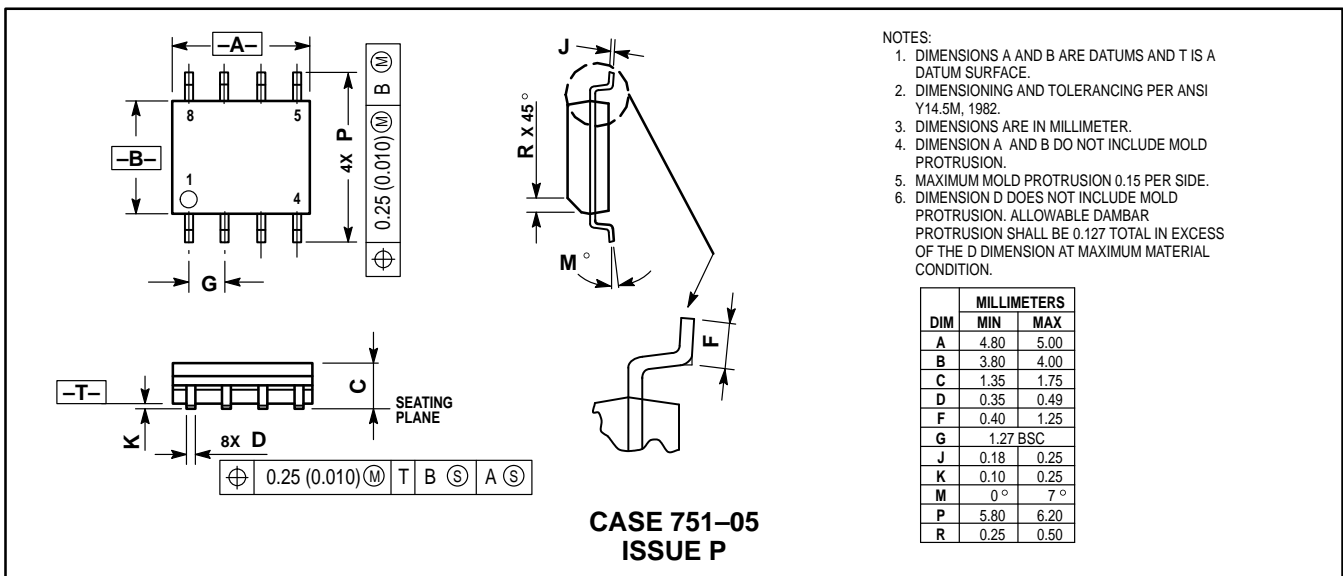
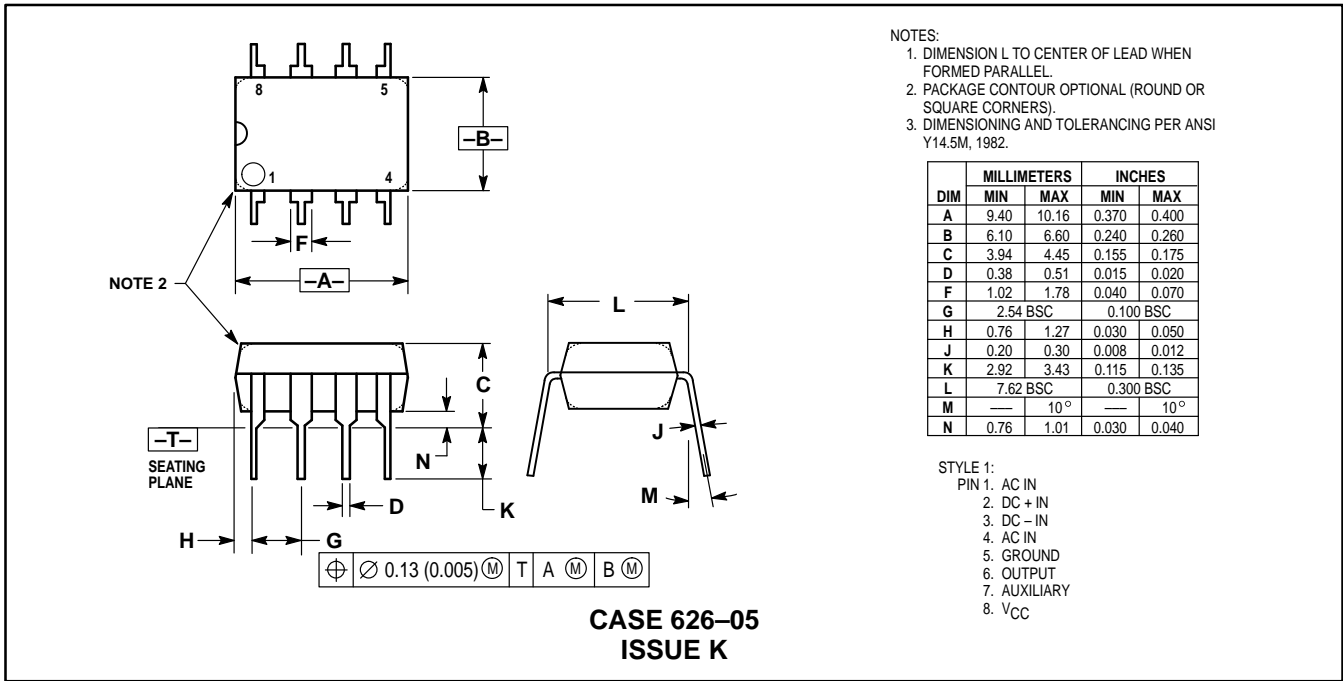



Figure 3. Deadtime Waveform Definitions

PACKAGE DIMENSIONS



Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters which may be provided in Motorola data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and  are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

**How to reach us:**

**USA/EUROPE/Locations Not Listed:** Motorola Literature Distribution;  
P.O. Box 20912; Phoenix, Arizona 85036. 1-800-441-2447 or 602-303-5454

**MFAX:** RMFAX0@email.sps.mot.com – TOUCHTONE 602-244-6609  
**INTERNET:** <http://Design-NET.com>

**JAPAN:** Nippon Motorola Ltd.; Tatsumi-SPD-JLDC, 6F Seibu-Butsuryu-Center,  
3-14-2 Tatsumi Koto-Ku, Tokyo 135, Japan. 03-81-3521-8315

**ASIA/PACIFIC:** Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park,  
51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852-26629298



**MOTOROLA**

